## D opant-m odulated pair interaction in cuprate superconductors

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Comparison of recent experimental STM data with single-impurity and many-impurity Bogoliubov-de Gennes calculations strongly suggests that random out-ofplane dopant atoms in cuprates modulate the pair interaction locally. This type of disorder is crucial to understanding the nanoscale electronic structure inhom ogeneity observed in BSCCO-2212, and can reproduce observed correlations between the positions of impurity atoms and various aspects of the local density of states such as the gap magnitude and the height of the coherence peaks. Our results imply that each dopant atom modulates the pair interaction on a length scale of order one lattice constant.

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The discovery of nanoscale inhomogeneity in the cuprates has recently generated intense interest. In particular, the spectral gap in the local density of states (LDOS), as observed by scanning tunneling m icroscopy (STM) [1, 2, 3, 4] in Bi<sub>2</sub>Sr<sub>2</sub>CaCu<sub>2</sub>O<sub>8+x</sub> (BSCCO), varies by a factor of two over distances of 20-30A. This unusual behavior m ay help reveal how the cuprates evolve from the Mott insulating state at half- lling to the superconducting state at nite doping. The hole concentration in the CuO<sub>2</sub>-planes of BSCCO is proportional to the num ber of out-ofplane dopant atom s, which also introduce disorder. This has led to the proposition that poorly screened electrostatic potentials of the dopant atom s generate a variation in the local doping concentration and thus give rise to the gap m odulations observed in STM [5, 6, 7]. Poor screening has also been argued to result in enhanced forward scattering [8], which appears to be compatible with photoem ission [9, 10] and transport m easurem ents [11] in the superconducting state of BSCCO.An alternate perspective is explored in several works which associate inhom ogeneous electronic structure with a competing order parameter, such as antiferrom agnetism [12, 13, 14]. Only very recently has it been possible to measure correlations between the inhomogeneities observed in STM and positions of dopant atom s [15], thus providing a clue to the relation between disorder and doping in this com pound, as well as a means to exam ine the above proposals.

In this Letter, we assume that the electronic inhom ogeneity observed by STM, at least in the optim ally to overdoped sam ples, can be understood within the fram ework of BCS theory in the presence of disorder. We show, however, that the conventional modeling of disorder as a set of random potential scatterers fails to reproduce the most prominent features of the STM experiments described above: (i) the subgap spectra are spatially extrem ely hom ogeneous [3], unless they are taken in the immediate vicinity of a defect in the CuO<sub>2</sub> plane, (ii) the coherence peaks in regions with larger gap tend to be much broader and reduced in height, (iii) the \coherence peak" positions are symmetric about zero bias,

(iv) the dopants are found to correlate positively with large gap regions [15]; and (v) charge modulations are sm all [15]. We propose that the dopant atom s m odulate the local pair potential, i.e. the local attractive coupling g between electrons is spatially dependent. In conventional superconductors, such e ects are di cult to observe because atom ic-scale m odulations in g produce LDOS modulations only on the scale of the coherence length 0. In the cuprates, how ever, the situation is different due to the short coherence length. W e dem onstrate that a model in which dopant atom s modulate the pair interaction gives excellent agreem ent with respect to the above m entioned key characteristics of the STM data. A modulated pair interaction could arise from local lattice distortions surrounding the dopant atom sm odifying the electron-phonon coupling or superexchange interaction in their vicinity.

M odel. W e consider the following mean-eld H am iltonian for a singlet d-wave superconductor

$$\hat{H} = \begin{pmatrix} X \\ k \end{pmatrix}_{k} \hat{C}_{k}^{V} \hat{C}_{k} + \begin{pmatrix} X \\ V_{i} \hat{C}_{i}^{V} \hat{C}_{i} + \begin{pmatrix} X \\ i \end{pmatrix}_{ij} \hat{C}_{j*}^{V} \hat{C}_{j\#}^{V} + H c.;$$
(1)

 $2t(\cos k_x + \cos k_y) = 4t^0 \cos k_x \cos k_y$ where k =hiji denotes sum mation over neighboring lattice and sites i and j. In the remainder of the paper we will set  $t^0 = t = 0.3$  and adjust to model the Ferm i surface of BSCCO near optim al doping (for the hom ogeneous system, =t=-1.0). In order to account for disorder in the out-of-plane dopants, which are separated from the  $CuO_2$  plane by a distance z, we include an impurity potentialm odeled by  $V_i = V_0 \exp(r_i = )=r_i$ , where  $r_i$  is the distance from a dopant atom to the lattice site i in the plane. Distances are measured in units of  $\frac{1}{2}a$ , where a is the Cu-Cu distance. The nearest-neighbor d-wave order parameter  $ij = g_{ij}h\hat{c}_{i''}\hat{c}_{j\#} \quad \hat{c}_{j\#}\hat{c}_{i''}i$  is determined self-consistently using (1) with  $g_{ij} = g + (V_i + V_j) = 2$ . In traditional BCS theory,  $g_{ij} = g$  is spatially uniform, and

 $_{ij}$  is only m odulated in the vicinity of potential scatterers [16, 17]. W e w ill argue that this approach is unable to reproduce observations (i)-(v) outlined above, and that

 $g_{\rm ij}$  is strongly modi  $\,$  ed near the dopant atom s.

Sm ooth potential. If the potential caused by the outof-plane dopant atom s were very smooth on the scale of 0, the local properties of the inhom ogeneous system would be determined by the local value of the disorder potential and the local value of the pairing interaction. Therefore one would expect an LDOS which is locally sim ilar to a clean superconductor with renorm alized chem ical potential  $V_i$  in the case of a smooth potential Vi, or with renorm alized bond order param eij for a smooth o -diagonal (OD) potential. ter <sub>ij</sub> + In the case of a conventional diagonal potential, a gap size m odulation will be induced because the gap is a relatively sensitive function of the local chem ical potential, see Fig. 1(a). On the other hand, modulations of this type will inevitably have coherence peak weight-position correlations opposite to experim ent, since large gap values in the hom ogeneous system im ply (within BCS theory) that spectral weight rem oved from low energies is transferred into the coherence peaks (Fig. 1(b)). This e ect is further enhanced by the presence of a van-Hove singularity at  $!_{vH} =$  $(4t^0 + )^2 + (4_0)^2$  in the tightbinding m odel which contributes additional weight to the coherence peaks, in particular for =t = 1.2 where it coincides with the gap edge. Here  $_0$  is the bond order param eter in the hom ogeneous system . A similar although less pronounced positive correlation between coherence peak weight and position arises also for the sm ooth OD case. Note that throughout this work we neglect inelastic scattering that would broaden the tunneling conductance peaks at large bias but would not change their weight, thus leaving our conclusions una ected.

Single-impurity scattering. Since a smooth disorder potential cannot reproduce the experimentally observed relation between the weight of the coherence peak and the gap magnitude, we now address the opposite limit, i.e. a very spiky potential caused by a dopant potential with short range on the scale of  $_0$ . Some insight into this situation can be obtained by analyzing singleim purity scattering processes, which should be dom inant

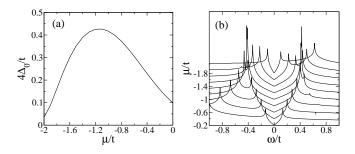


FIG.1: (a) Order parameter 0 for t<sup>0</sup>=t = 0.3 and a constant nearest neighbor attraction of g=t = 1:16 as a function of chem ical potential . (b) Local density of states for di erent using the order parameter displayed in (a).

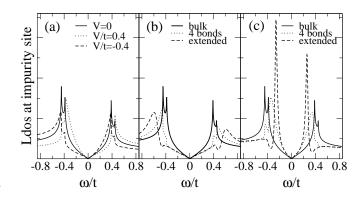


FIG. 2: On-site LDOS for di erent single-in purity models with  $t^0=t=0.3$ , =t=1 and  $_0=t=0.1$ . (a) W eak point-like potential scatterer. (b) D otted line: attractive \pointLike" OD scatterer with  $= _0$  on the four bonds surrounding the in purity site. D ashed line: extended attractive OD scatterer with = z = 1. (c) Same as (b), with  $= _0$ .

for su ciently short ranged and weak scattering potentials, where interference e ects are negligible. For sim – plicity we assume constant order parameter in the following T-matrix analysis and postpone the fully selfconsistent treatment to the many in purity case.

A lthough solving the T-m atrix equation for the potential scatterer  $V_i$  = V $_{i0}$  is straightforward [18], relatively little attention has been paid to the weak to interm ediate strength in purity case V . tbecause it does not lead to well-de ned resonant states inside the gap. Fig. 2 (a) show s the LD O S at the in purity site for a weak pointlike potential scatterer. The positions of the coherence peaks are hardly shifted at all, and while the spectral weight of the coherence peaks is modi ed, this occurs in a distinctly particle-hole asymmetric fashion. This is in striking contrast to the STM spectra, where inhom ogeneous but particle-hole symmetric coherence peak m odulations are observed. In addition, there is no distinct feature in experiment corresponding to the van Hove features present, as e.g. in Figs. 1 (b) and 2 (a).

These shortcom ings of the conventional potential scattering model can be overcome by considering OD scattering instead. For the sake of clarity, in this paragraph we neglect the diagonal component of the potential. Fig. 2(b) and Fig. 2(c) show the LDOS at the im purity site for a \pointlike" OD scatterer with d-wave symmetry on the four bonds emanating from site i = 0, 0; x = , and a m ore extended O D scat-0; ∲  $(V_i + V_j) = (2V_0)$ , where  $V_i$  is deterer with ij = ned below Eq. (1) and the negative sign applies to bonds oriented along the ŷ-direction. Scattering at an order param eter enhancem ent (see Fig. 2 (b)) strongly suppresses the coherence peaks for large values of ormoreex-

the coherence peaks for large values of or more extended OD scatterers. For scattering by a local order parameter suppression (see Fig. 2 (c)), exactly the opposite happens: an Andreev resonance form s just below the gap edge, sim ilar to the case where the order param eter is suppressed near surfaces [19, 20]. For large negative values of  $\$ , or m ore extended O D scatterers, the Andreev resonance m oves to sm aller energies, and its peak height increases. It draws m ost of its spectral weight from the van H ove singularity at (;0), which is close to the part of the Ferm i-surface with the largest d-wave gap, i.e., the part which is m ost a ected by order param eter m odulations. A lthough this indicates that the weight of the resonance depends on band structure, we md that the phenom enon is very robust over a wide range of t<sup>0</sup> and .

M any-impurity results. In order to strengthen our argument for dopant-modulated pairing interaction we now address the e ect of self-consistency and interference between many impurities. To this end, we solve self-consistently the Bogoliubov-de Gennes (BdG) equations resulting from Eq.(1), on a 80–80 lattice rotated by =4 compared to the Cu-O bond direction (as in experimental STM m aps), i.e., our system contains 2–80<sup>2</sup> lattice sites in total. A ssum ing the dopants are interstitialoxygens, each onem ost likely contributes two holes to the CuO<sub>2</sub> plane. We therefore consider a dopant concentration of 7.5% for optim al doping which are distributed random ly in the reservoir layer separated from the CuO<sub>2</sub> plane by a distance z.

In the  $\lim_{t \to 0} t$  of a smooth potential (Fig. 3(a)), the m any-im purity results agree wellw ith the local picture discussed above. The correlation between the dopant positions and the gap amplitude depends strongly on the size of the potential due to the non-monotonic dependence of  $_0$  on the local , as shown in Fig. 1(a). The spatial variation of the gap, however, is not rapid enough to reproduce the grainy gap maps seen experimentally with gap \patches" of typical size 20-30A [3]; one is therefore forced to consider \spikier" potentials (Fig. 3(b)). In the weak limit V . t, one recovers the results of the single-in purity case, i.e., the coherence peaks are modulated in a particle-hole asymmetric way. For the stronger spiky potentials required to reproduce the magnitude of the gap modulations observed in STM, subgap states start to form in contradiction with experiment (see 3 (b)). Further discrepancies between Figs. 3(a) and 3(b) and the experimental spectra are: i) the LDOS clearly does not exhibit the inverse relation between gap size and coherence peak height; ii) the spectra are quite particle-hole asymmetric (see Fig. 3 (b) and high energy regions in Fig. 3(a)); and iii) the sizable potential required to induce gap m odulations inevitably leads to large (0 (50% 100%)) local charge m odulations. The latter point puts strong constraints on any potential scattering m odel, since the prim ary role of the im purity potential is to couple to the density.

A typicalLDOS line scan for a m any OD in purity calculation is shown in F ig.3 (c). Note that, by construction, this m odel has hom ogeneous low -energy LDOS as well as strong correlations between the dopant positions and the

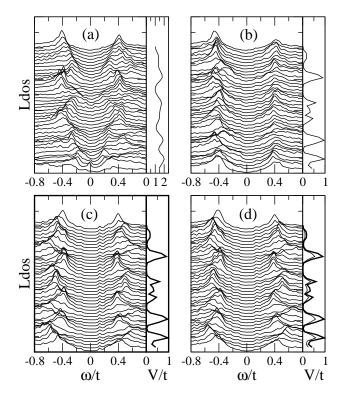


FIG.3: LDOS from self-consistent solution of BdG equations, along a straight line for (a) conventional potential with z = 2,  $= 2, V_0 = 1.5t$ ; (b) same as (a), but with z = 0.57, = 0.5; (c) OD potential with  $V_i$  as in (b); and (d), combination of OD potential shown in (c) with conventional potential as in (b) but with  $V_0 = 0.6t$ . Conventional (OD) potentials are depicted to right of each panel as a thin (thick) line.

local gap values. As in the single in purity case, the lineshape of the LDOS near the gap edge is determ ined primarily by Andreev scattering. Because the LDOS near the gap edge is rem in iscent of a coherence peak, we will simply adopt this term inology, as used in experiment. The dopant atom s inevitably give rise to a conventional potential as well, how ever; we therefore show in Fig. 3 (d) that the qualitative features of OD scattering depicted in Fig. 3 (c) survive this scattering. C om paring Figs. 3 (ad), it is evident that the OD LDOS spectra are farm ore particle-hole symmetric than those with potential disorder, and display the inverse relation between gap magnitude and coherence peak height, as expected from the single-im purity discussion (see Fig. 2). In Fig. 4 we show the associated gap m ap (a), the coherence peak height map (b), and the charge modulation map (c) for param eters corresponding to Fig. 3(c). Fig. 4(d) displays the correlation functions between the gap m ap and the dopants, and the gap m ap and the peak height m ap [21]. The local pairing m odulation shown in Fig. 4 reproduces qualitatively the correct negative correlation between the gap am plitude and the coherence peak height, the positive correlation between dopant atom locations and large gap values, and the relatively sm all charge m odulations

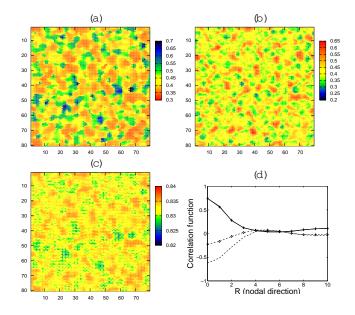


FIG.4: (Color online.) M any OD in purity m odel for parameters of Fig.3(c): (a) 2D real-space m ap of the local coherence peak position (gap) in units of t; (b) coherence peak height (note the inverse color scale with respect to (a)); (c) total charge (note the sm all scale); and (d) the correlation function between the gap m ap and the dopant atom s (solid), and the gap m ap and the peak height m ap (dashed). Lines without (with) sym bols correspond to the param eters used in Fig.3(c) (Fig.3(d)).

observed in experiment [15]. In addition, the spectra exhibit the same remarkable particle-hole symmetric modulations of the coherence peaks observed in experiment [3]. This symmetry should manifest itself in Fourier transform quasiparticle interference patterns as well.

In the OD scattering model, short-distance correlations between the dopant atoms and the gap size are nearly perfect, as seen in Fig. 4(d); indeed, they are considerably stronger than reported in experiment [15]. This might be due to the di culty of identifying all dopant positions experimentally, to the presence of additional cation disorder in BSCCO [22], or to the nite experimental resolution of the dopant resonances. The dopantgap correlations are quite robust against inclusion of a conventional scattering component (the two solid curves in Fig. 4(d) coincide), but the gap-peak height correlations are rapidly suppressed, as seen in Fig. 4(d).

A natural question is the extent to which these correlations are robust against di erent choices of param – eters. We nd that the local spectral properties in the spiky regime of the OD m odel are insensitive to param – eters, provided the amplitude of the gap m odulation is comparable to or larger than the splitting of the van H ove and coherence peaks in the pure system. In that case the weight of the van H ove peak is absorbed into the coherence peak (F ig. 2 (c)).

W hile we assert the prim acy of the OD channel of scat-

tering for the m odulation of the states near the antinode, we emphasize that nodal quasiparticles are very weakly scattered by this potential, and so m icrow ave and therm altransport are probably only m inim ally in uenced by the e ects discussed here [11]. This further im plies that the elastic contribution to the ARPES spectral peaks near the antinodal and nodal points are determ ined by com pletely di erent scattering processes.

Conclusions. The discovery of nanoscale inhom ogeneity in the local electronic structure of BSCCO-2212 [1, 2, 3, 4] has provoked an intense discussion about the origin of this phenom enon in cuprates and related correlated electron materials. In this work, we have offered strong evidence that the inhom ogeneity in the coherence peak position is in fact driven by dopant atom s, located away from the CuO<sub>2</sub> plane, whose primary elect on one-particle properties is to modulate the local pair interaction. This ansatz allowed us to reproduce, in model single-in purity and many-in purity calculations, most of the important correlations observed in recent STM experiments.

The calculations reported here have been done entirely within a BCS fram ework, and as such cannot be expected to reproduce certain other correlations, such as the increase of the average gap with underdoping. Nevertheless, we believe that our results represent an important step towards further m odeling which m ay reveal the m icroscopic nature of the m odulated pair interaction.

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